



Belle II



# Status of the Silicon Strip Vertex Detector of the Belle II Experiment

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Vertex 2013 Lake Starnberg

16 September 2013









## **Belle and Belle II**

Components Sensors Electronics Mechanics and Cooling Ladder assembly Mockups Summary





# Belle I at the KEKB accelerator (1999-2010)

### Belle I:

- Measurements of CKM matrix elements and angles of the unitary triangle
- CP & T & CPT test
- Observation of direct CP violation in B decays
- probe for new sources of CPV

### KEKB accelerator:

- Center of mass energy: Y(4S) resonance (10.58 GeV)
- High intensity beams (1.6 A & 1.3 A)
- Integrated luminosity of 1 ab<sup>-1</sup> recorded in total







e<sup>+</sup> 4GeV 3.6 A

Belle II

New IR

# SuperKEKB/Belle II Upgrade: 2010–2015

- 40-fold increase in peak luminosity to  $8 \times 10^{35} \text{ cm}^{-2} \text{s}^{-1} \rightarrow 1 \times 10^{10} \text{ BB}$  / year
- 50-fold increase in integrated luminosity until 2023 w.r.t. Belle I
- Refurbishment of accelerator and detector required
  - nano-beams with cross-sections of ~10 µm x 60 nm
  - 2 cm diameter beam pipe at interaction region



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## **Belle Silicon Vertex Detector (SVD) until 2010**



- 4 straight layers of 4" double-sided silicon detectors (DSSDs)
- Outer radius of r~8.8 cm
- Acceptance angle 17° ...150°
- Up to three 4" sensors were daisy-chained and read out by one hybrid located outside of acceptance region (VA1 chip)







# **Belle SVD limitations**

- Previous SVD limitations were
  - occupancy

     (10%-18% in innermost layer)
     → need faster shaping or
     smaller detector elements
  - dead time
     → need faster readout and pipeline
- Belle II needs detector with
  - high background tolerance
  - pipelined readout
  - robust tracking
  - low material budget in active volume



# Previous SVD is not suitable for Belle II !





# New Layout for Belle II SVD (2015-)

Four layers with 6" doublesided strip detectors at larger radii and forward part

- Large, individually read out sensors
- FE readout electronics inside acceptance region
- Maintain low material budget
  - Lightweight mechanics
  - Thin cooling pipes  $(CO_2)$
- Fast readout

Layer 3 to 6: 4 layers of double-sided strip sensors

| Layer<br>Two la<br>DEPFE | 1-2:<br>byers of<br>ET pixels |        |         |
|--------------------------|-------------------------------|--------|---------|
| ···                      | Layer                         | Radius | Ladders |
|                          | 6                             | 135 mm | 16      |
|                          | 5                             | 104 mm | 12      |
|                          | 4                             | 80 mm  | 10      |
|                          | 3                             | 38 mm  | 7       |





# **Current Status**

- Transition from R&D to production phase
- Milestones defined by Belle II schedule
  - SVD ladder assembly Nov. 2013 Sept. 2014
  - Ladder mount: Sept. 2014 August 2015
  - SVD ready by August 2015
  - VXD (PXD+SVD) ready by January 2016
  - VXD installation June 2016

### Components

- Sensors
- Front-end and backend electronics
- Mechanics design
- CO<sub>2</sub> cooling
- Ladder assembly and lab infrastructure
- Mockups













## Belle and Belle II Components Sensors

Electronics Mechanics and Cooling Ladder assembly Mockups Summary





# **Double-sided strip sensors from 6" wafers**

**Sensor Properties:** 

- Double-sided with perpendicular strips
- AC-coupled readout with poly-silicon resistor
- N-bulk, 300/320 micron thickness
- Three layouts only:
  - Rectangular small for layer 3 (HPK)
  - Rectangular large for layers 4-6 (HPK)
  - Trapezoidal for forward layers 4-6 (Micron)



|                | Readout<br>strips(p/R∳<br>) | Readout<br>strips(n/z) | Readout<br>pitch (p/Rø) | Readout<br>pitch(n/z) | Sensors #<br>(+ spares) | Active area<br>(mm <sup>2</sup> )  |
|----------------|-----------------------------|------------------------|-------------------------|-----------------------|-------------------------|------------------------------------|
| Large          | 768                         | 512                    | 75 µm                   | 240 µm                | 120+18                  | 122.90x57.72<br>=7029.88           |
| Trapezoidal    | 768                         | 512                    | 50-75 µm                | 240 µm                | 38+6                    | 122.76x(57.59+38.42)<br>/2=5893.09 |
| Small          | 768                         | 768                    | 50 µm                   | 160 µm                | 14+4                    | 122.90x38.55<br>=4737.80           |
| 16 September 2 | 2013                        | Thomas Be              | ergauer (HEPHY          | Vienna)               |                         | 10                                 |





# **Rectangular sensors (HPK)**

- Small DSSDs
  - Delivery of 24 pcs. scheduled for end of September
  - Two mechanical samples available
- Large DSSDs:
  - Production finished
  - 150 pcs in hand











# **Trapezoidal Sensors for Forward Region**







## eta distribution for atoll p-stop



Charge accumulation in unimplanted region

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# Signal-to-noise-ratios

- Test sensors have been Gamma-irradiated with Co-60 (70 Mrad) in Mol (Belgium)
- Tested before and after at CERN beam test (H6A 120 GeV hadrons)





**Combined p-stop** 



- Dark colors: non-irradiated, Light colors: irradiated
- Atoll pattern (half-wide) performs best, both irradiated and nonirradiated
  - Chosen for final sensor, 100 wafers currently being processed by Micron





## **Beam test results**

- Performance of full modules verified in several beam tests at CERN (2008-2012)
  - Including CO<sub>2</sub> cooling
  - Using EUDET and own beam telescope



Double Origami module



| FW wedge | module |
|----------|--------|
|----------|--------|



| Irrad  | Origami #4 |      | Origami #3 |      | Wedge #1 |      |
|--------|------------|------|------------|------|----------|------|
|        | р          | n    | р          | n    | р        | n    |
| Before | 12.2       | 22.7 | 12.0       | 23.4 | 14.9     | 13.0 |
| After  | 11.9       | 16.0 | 12.6       | 23.4 | 12.6     | 12.0 |

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## Belle and Belle II Components Sensors Electronics Mechanics and Cooling Ladder assembly Mockups Summary





## **Readout System Concept**



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# **Readout Chip: APV25**

- Developed for CMS (LHC) by Imperial College London and Rutherford Appleton Lab
  - 70.000 chips installed
- 0.25 µm CMOS process (>100 MRad tolerant)
- 128 channels
- 192 cell analog pipeline
   → almost no dead time
- 50 ns shaping time  $\rightarrow$  low occupancy
- Multi-peak mode (read out several samples along shaping curve)
- Noise: 250 e + 36 e/pF
   → must minimize capacitive load!!!
- Thinning to 100µm successful









# **Origami Chip-on-Sensor Concept**

- Chip-on-sensor concept for double-sided readout
- Flex fan-out pieces wrapped to opposite side (hence "Origami")
- All chips aligned on one side → single cooling pipe











# **APV25 – Hit Time Reconstruction**

- Possibility of recording multiple samples (x) along shaped waveform (feature of APV25)
- **Reconstruction of** Ś Peak time precision vs. SNR peak time (and 10 amplitude) SPS June 2008 9 KEK Nov 08 standard by waveform fit KEK Nov 08 doubled IPRE 8 KEK Nov 08 31.8 Mhz Signal [e Using LUT in FPGA SPS Aug 09 run042 7 SPS Aug 09 run043 SPS Aug 09 run6873 Is used to 6 l s n s n s n SPS Aug 09 run012 SPS Aug 09 run019 remove off-time 5 Theory 4 background hits 3 2...3 ns RMS 2 accuracy at 1 typical S/N 0

5

10

15

Cluster SNR

20

25

0

30





# **Occupancy Reduction Belle -> Belle II**











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# **SVD Ladders**









- Basic element "atomic unit" is one ladder
- Only FW and BW module can be assembled independently
- No single Origami module with one sensor possible





# Material Budget of a ladder

- Largest peak contribution by
  - Cooling pipe
  - Support ribs



## Components:

- Single cooling pipe
- Thinned APV25 (100µm)
- 3-layer flex circuit
- Connection to Strips:
  - PA on top side
  - wrapped PA for bottom
- 1mm Airex sheet
- 6" DSSD
- CF support ribs

• Average Material Budget: 0.59%X<sub>0</sub>





# **Support Ribs**



- 3mm Airex core with laminated
   0.15mm CF sheets
- Very stiff, yet lightweight thanks to the sandwich construction









# CO<sub>2</sub> cooling system

- IBBelle Prototype "MARCO" (Multi-Purpose Apparatus for Research in CO<sub>2</sub>)
  - Power ~ 1 kW
- Based on concept by NIKHEF (B. Verlaat)
- CO<sub>2</sub> plant shared with PXD
- Development in collaboration between PXD group (MPI), CERN and NIKHEF
- Ladder production sites uses small open (blow) CO<sub>2</sub> system

Vienna open CO<sub>2</sub> system













Belle and Belle II Components Sensors Electronics Mechanics and Cooling Ladder assembly Mockups Summary





# **SVD ladder assembly flow**

- Three modules types:
  - Forward (FW)
  - Backward (BW)
  - Origami
- Ladder assembly sites:

| Layer   | Institute            |
|---------|----------------------|
| 3       | Melbourne (AUS)      |
| 4       | TIFR India @ IPMU    |
| 5       | HEPHY Vienna (AT)    |
| 6       | Kavli IPMU (Japan)   |
| FW & BW | INFN Pisa (possibly) |







# **Assembly Jigs**

# Huge number of different jigs (up to 17) necessary:

| Nr. | Jig name              | Purpose of jig                                   | Status (L5) |
|-----|-----------------------|--|-------------|
| 1   | Assembly base         | Align jigs to each other                         | designed    |
| 2   | Assembly bench        | Carry Origami sensor, align jigs                 | designed    |
| 2.1 | Forward sensor inlay  | Carry forward sensor during assembly             |             |
| 2.2 | Backward sensor inlay | Carry backward sensor during assembly            |             |
| 2.3 | Origami sensor inlay  | Support Origami sensors                          |             |
| 3   | Sensor jig            | Fix sensors to attach bottom-side pitch adapters | produced    |
| 4   | PA1 jig               | Align and glue PA1                               | produced    |
| 5   | PA2 jig               | Align and glue PA2                               | produced    |
| 6   | xytheta stage         | Precise alignment of sensors                     |             |
| 7   | Airex jig             | Align and attach Airex sheet                     |             |
| 8   | Origami alignment jig | Align Origami flexes                             |             |
| 9   | Origami ce jig        | Pick up and glue Origami ce flex                 |             |
| 10  | Origami -z jig        | Pick up and glue Origami -z flex                 |             |
| 11  | PF2 jig               | Attach pitch adapter (PF2)                       |             |
| 12  | PB2 jig               | Attach pitch adapter (PF2)                       |             |
| 13  | Slant jig             | Glue forward sensor onto ribs                    |             |
| 14  | Backward jig          | Glue backward sensor onto ribs                   |             |
| 15  | Rib jig               | Mount and align ribs                             |             |
| 16  | CO2 clamp jig         | Attach CO2 cooling pipe clamps                   | designed    |

|           | СММ                 | XYZ0-stg              | bench         | base         | Sensor-jig   | Status      |
|-----------|---------------------|-----------------------|---------------|--------------|--------------|-------------|
| Melbourne | Mitsutoyo QV-PRO302 | KIPMUdesign+<br>1comp | 1             | Draft design | Draft design |             |
| TIFR      | Sharing with KIPMU  | Sharing               | manufacturing | 1            | 1            |             |
| HEPHY     | Mitsutoyo Euro-C776 | In progress           | designed      | designed     | 1            |             |
| KIPMU     | Mitsutoyo QV-606    | 1                     | 1             | 1            | 1            | Finalizing? |
| INFN      | Mitsutoyo F604      | designing             | -             | -            | designing    |             |

| igs                        |             | XYZÐ-stage     |
|----------------------------|-------------|----------------|
| Sens                       | or jig      |                |
|                            | •           | Assembly base  |
|                            |             |                |
| Sensor-jig<br>Draft design | Status      |                |
| 1                          |             |                |
| 1                          |             | 12 49: 1       |
| 1                          | Finalizing? | 0 0            |
| designing                  |             | Assembly bench |
|                            |             |                |

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# **Alignment of Jigs**

- Using linear bushings (+0/-13µm) & precision pins (g6)
- Assembly base & bench are reference
  - All linear bushings are fixed bearings  $\rightarrow$  high precision holes (H7)
- All other jigs are aligned to them, e.g. Sensor jig







# Ladder assembly equipment

- Coordinate Measurement machines (Mitutoyo)
- Glue dispensing robots
  - CMM used as glue robot in Vienna
- Fully-automatic wire bonders
- (lot of) manpower and ideas







Automatic wire bonder Choonpa Co. REBO-7W IPMU(borrowed KEK)



HEPHY, TIFR)





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# Ladder assembly procedure

alignment w/ XYZθ-stage

- Two weeks per ladder expected
- Bonding/glue-curing interlaced

Assembly-jig

 Wire bonding between DSSD n-side and ORIGAMI PCB is done.
 Pitch adapters from P-side are wrapped and glued to top of ORIGAMI.
 The high-density wire bonding between the Pitch adapter to the APV25 chip is done.

Next steps are most difficult and require care.

Finish

Animation of (simplified) procedure

### Thomas Bergauer (HEPHY Vienna)

DSSD









Belle and Belle II Components Sensors Electronics Mechanics and Cooling Ladder assembly Mockups

**Summary** 





# Mockup IR-PXD-SVD







# **Going real!**







# **PXD+SVD Testbeam @ DESY**

- Test of "full" VXD
  - 2 Layers DEPFET
  - All 4 layers of SVD (one sensor per layer only)
  - Inside PCMAG superconducting magnet
  - MARCO CO<sub>2</sub> cooling plant
  - Full readout chain
- 4 weeks beamtime at DESY TB24 in January 2014
  - Connectivity test end of June in Vienna to test connection between SVD FADC, FTB, DataCon
  - Installation in zone starting end of November 2013













Belle and Belle II Components Sensors Electronics Mechanics and Cooling Ladder assembly Mockups Summary





# Summary

- SuperKEKB will be the highest luminosity machine in the world
- Belle II detector will consist of new, enlarged Silicon Vertex Detector
  - 2 layers DEPFET Pixels (PXD) and
  - 4 double-sided strip layers (SVD)
- Strip Detector (SVD)
  - Double Sided Strip Detectors



- Optimal p-stop geometry identified by SNR measurements before and after irradiation
- Chip-on-sensor readout scheme, named Origami, for outermost three layers for low material budget, using CF ribs and CO<sub>2</sub> cooling
- Readout with hit time reconstruction for improved background tolerance
- Mass production of ~50 ladders starts this fall, SVD ready by 2015









## The End.

**Backup Slides follow** 





# **Belle Detector (1999–2010)**







# **Belle II Detector**

K<sub>L</sub> and muon detector: Resistive Plate Counter (barrel outer layers) Scintillator + WLSF + MPPC (end-caps, inner 2 barrel layers)

EM Calorimeter: CsI(TI), waveform sampling (baseline) (opt.) Pure CsI for end-caps

electron (7GeV)

Beryllium beam pipe 2cm diameter

Vertex Detector 2 layers DEPFET + 4 layers DSSD

> Central Drift Chamber He(50%):C<sub>2</sub>H<sub>6</sub>(50%), Small cells, long lever arm, fast electronics

Particle Identification Time-of-Propagation counter (barrel) Prox. focusing Aerogel RICH (fwd)

positron (4GeV)





## Spatial Resolution of the Belle II Detector







## **Sensor Types and Vendors**



| Layer | # of<br>Ladders | Rect. Sensors<br>[narrow] | Rect. Sensors<br>[wide] | Wedge<br>Sensors | APVs |
|-------|-----------------|---------------------------|-------------------------|------------------|------|
| 6     | 16              | 0                         | 64                      | 16               | 800  |
| 5     | 12              | 0                         | 36                      | 12               | 480  |
| 4     | 10              | 0                         | 20                      | 10               | 300  |
| 3     | 7               | 14                        | 0                       | 0                | 168  |
| Sum:  | 45              | 14                        | 120                     | 38               | 1748 |

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# **HPK Pinholes**







# **Sensor Parameters**

## **Rectangular Sensors**

| Quantity                        | Large sensor                    | Small sensor                    |
|---------------------------------|---------------------------------|---------------------------------|
| # strips $p$ -side              | 768                             | 768                             |
| # strips $n$ -side              | 512                             | 768                             |
| # intermediate strips $p$ -side | 767                             | 767                             |
| # intermediate strips $n$ -side | 511                             | 767                             |
| Pitch <i>p</i> -side            | $75\mu{ m m}$                   | $50\mu{ m m}$                   |
| Pitch <i>n</i> -side            | $240\mu{ m m}$                  | $160\mu{ m m}$                  |
| Area (total)                    | $7442.85{ m mm^2}$              | $5048.90{ m mm^2}$              |
| Area (active)                   | $7029.88 \mathrm{mm^2}$ (94.5%) | $4737.80 \mathrm{mm^2}$ (93.8%) |

| Quantity                         | Value  |
|----------------------------------|--|
| Base material                    | Si <i>n</i> -type $8 \mathrm{k}\Omega \mathrm{cm}$ |
| Full depletion voltage FD        | $< 120 \mathrm{V}$                                 |
| Breakdown voltage                | $\geq { m FD} + 50 { m V}$                         |
| Polysilicon resistor             | $4 M\Omega$ (min.), $10 M\Omega$ (typ.)            |
| Coupling capacitance             | $> 100 \mathrm{pF}$                                |
| Breakdown voltage of AC coupling | $> 20 \mathrm{V}$                                  |
| Bias leak current at FD          | $1 \mu A$ (typ.), $10 \mu A$ (max.)                |

## **Trapezoidal Sensors**

| Quantity                       | Value                         |
|--------------------------------|-------------------------------|
| # strips <i>p</i> -side        | 768                           |
| # strips <i>n</i> -side        | 512                           |
| # intermediate strips $p-side$ | 767                           |
| # intermediate strips $n-side$ | 511                           |
| Pitch <i>p</i> -side           | $75\dots 50\mu{ m m}$         |
| Pitch <i>n</i> -side           | $240 \mu m$                   |
| Area (total)                   | $6382.6\mathrm{mm^2}$         |
| Area (active)                  | $5890 \mathrm{mm^2} (92.3\%)$ |
|                                | Layer 6: 21.1°                |
| Slant angles                   | Layer 5: 17.2°                |
|                                | Layer 4: 11.9°                |

| Quantity                              | Value  |  |  |  |
|---------------------------------------|--|--|--|--|
| Base material                         | Si <i>n</i> -type $8 \text{ k}\Omega \text{cm}$                              |  |  |  |
| Full depletion voltage FD             | 40 V (typ.), 70 V (max.)   |  |  |  |
| Operation voltage                     | $FD \dots 2 \times FD$   |  |  |  |
| Breakdown voltage                     | $\geq 2.5 	imes 	ext{FD}$  |  |  |  |
| Polysilicon resistor                  | $10 \text{ M}\Omega \text{ (min.)}, 15 \pm 5 \text{ M}\Omega \text{ (max.)}$ |  |  |  |
| Interstrip resistance, $p$ -side      | $100 \text{ M}\Omega \text{ (min.)}, 1 \text{ G}\Omega \text{ (typ.)}$       |  |  |  |
| Interstrip resistance, <i>n</i> -side | $10 \mathrm{M\Omega}$ (min.), $100 \mathrm{M\Omega}$ (typ.)                  |  |  |  |

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## **Current Barrel Layout**

| Layer | Sensors/<br>Ladder | Origamis/<br>Ladder | Ladders | Length [mm] | Radius [mm] | Slant Angle [°] |
|-------|--------------------|---------------------|---------|-------------|-------------|-----------------|
| 3     | 2                  | 0                   | 7       | 262         | 38          | 0               |
| 4     | 3                  | 1                   | 10      | 390         | 80          | 11.9            |
| 5     | 4                  | 2                   | 12      | 515         | 104         | 16              |
| 6     | 5                  | 3                   | 16      | 645         | 135         | 21.1            |









# **Origami Prototype Modules**

• Single Origami module (layer 4)



## • Double Origami module (layer 5)







# **Material budget**

| DSSD+ Origami  | Rib   | DSSD  | Airex<br>sheet | Origami | CO2<br>Cooling | 100 μm<br>Glue | Total |
|----------------|-------|-------|----------------|---------|----------------|----------------|-------|
| HPK+10RIGAMI   | 0.035 | 0.340 | 0.055          | 0.133   | 0.037          | 0.033          | 0.593 |
| HPK+2ORIGAMI   | 0.035 | 0.340 | 0.055          | 0.266   | 0.037          | 0.033          | 0.733 |
| Micron         | 0.035 | 0.320 | 0.055          | 0       | 0              | 0.011          | 0.421 |
| Micron+ORIGAMI | 0.035 | 0.320 | 0.000          | 0.133   | 0              | 0.033          | 0.576 |

- PA/PE/PB/SMD/ are neglected.
- Thickness of epoxy glue in ladder assembly is assumed to be 100  $\mu$ m, or, 0.033 % X<sub>0</sub>.







# **Breakdown of material budget**







# **Comparison VA1TA – APV25**

## VA1TA (SVD)

- Commercial product (IDEAS)
- Tp = 800ns (300 ns 1000 ns)
- no pipeline
- <10 MHz readout</li>
- 20 Mrad radiation tolerance
- noise: ENC = 180 e + 7.5 e/pF
- time over threshold: ~2000 ns
- single sample per trigger

## APV25 (Belle-II SVD)

- Developed for CMS by IC London and RAL
- Tp = 50 ns (30 ns 200 ns)
- 192 cells analog pipeline
- 40 MHz readout
- >100 Mrad radiation tolerance
- noise: ENC = 250 e + 36 e/pF
- time over threshold: ~160 ns
- multiple samples per trigger possible (Multi-Peak-Mode)





# **Status of Belle II Readout Electronics**

- Pre-production is driven by DESY beam test (January 2014)
  - first version of all boards to be used there
- Design is done; most parts of hardware exist already







# **Cooling Boundary Conditions**

- Power dissipation per APV: 0.40 W
- 1 Origami sensor features 10 APVs

| heat<br>amount<br>[W] | APV   | pipe | end-<br>ring | cone<br>(L3/4) | cone<br>(L5+6) | cable | Origami | hybrid | total |
|-----------------------|-------|------|--------------|----------------|----------------|-------|---------|--------|-------|
| end-ring<br>(FWD)     | 92.8  | 20.0 | 7.0          | 18.9           | 13.8           | 29.2  |         | 13.3   | 195.0 |
| end-ring<br>(BWD)     | 92.8  | 15.0 | 9.1          | 32.2           | 6.8            | 29.2  |         | 13.3   | 198.4 |
| Origami<br>(L6)       | 94.0  | 19.6 |              |                |                |       | 7.4     |        | 121.0 |
| Origami<br>(L5+4)     | 68.0  | 20.0 |              |                |                |       | 5.2     |        | 93.2  |
| total                 | 347.6 | 74.6 | 16.1         | 51.1           | 20.6           | 58.4  | 12.6    | 26.6   | 607.6 |

## •Total SVD power dissipation: 607 W





# **Baseline Schedule**













# **Glue Dispension**

### **Thickness of PA2+glue**











# **Idea of Ladder Mount Stage**

Rotation axis with encoder

